

# HD74HC152

1-of-8-line Data Selector/Multiplexer

REJ03D0576-0200 (Previous ADE-205-450) Rev.2.00 Oct 11, 2005

### Description

This data selector/multiplexer contains full-on-chip binary decoding to select the desired data source. The HD74HC152 selects one-of-eight data sources.

#### Features

- High Speed Operation:  $t_{pd}$  (Any D to W) = 17 ns typ ( $C_L = 50 \text{ pF}$ )
- High Output Current: Fanout of 10 LSTTL Loads
- Wide Operating Voltage:  $V_{CC} = 2 \text{ to } 6 \text{ V}$
- Low Input Current: 1 µA max
- Low Quiescent Supply Current:  $I_{CC}$  (static) = 4  $\mu$ A max (Ta = 25°C)
- Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74HC152P	DILP-14 pin	PRDP0014AB-B (DP-14AV)	Ρ	
HD74HC152RPEL	SOP-14 pin (JEDEC)	PRSP0014DE-A (FP-14DNV)	RP	EL (2,500 pcs/reel)

Note: Please consult the sales office for the above package availability.

### **Function Table**

	Select inputs		Output		Output		
С	В	Α	W	С	В	Α	W
L	L	Ļ	$\overline{D}_0$	Н	L	L	$\overline{D}_4$
L	L	Н	$\overline{D}_1$	Н	L	Н	$\overline{D}_5$
L	Н	L	$\overline{D}_2$	Н	Н	L	$\overline{D}_6$
L	н	H	$\overline{D}_3$	Н	Н	Н	$\overline{D}_7$

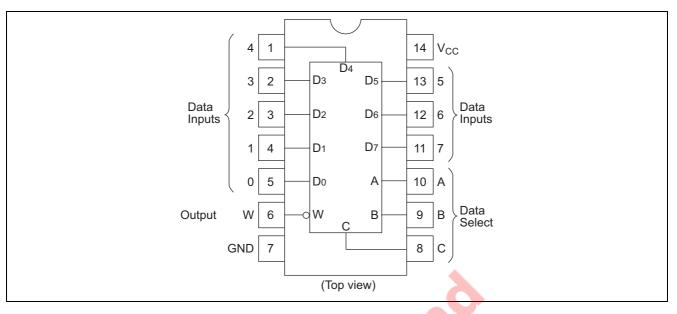
Note:  $D_0$  to  $D_7$ : the level of the D respective input

H: High level

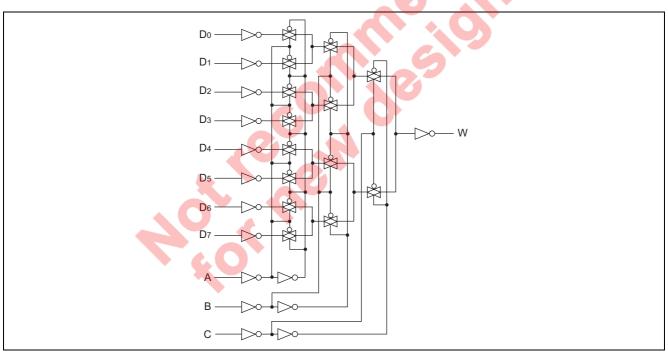
L: Low level



## **Pin Arrangement**



# Logic Diagram



# **Absolute Maximum Ratings**

ltem	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	-0.5 to +7.0	V
Input voltage	V <sub>IN</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
Output voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
Output current	I <sub>OUT</sub>	±25	mA
DC current drain per V <sub>CC</sub> , GND	I <sub>CC</sub> , I <sub>GND</sub>	±50	mA
DC input diode current	l <sub>ik</sub>	±20	mA
DC output diode current	Ι <sub>ΟΚ</sub>	±20	mA
Power dissipation per package	PT	500	mW
Storage temperature	Tstg	-65 to +150	°C

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

### **Recommended Operating Conditions**

Item	Symbol	Ratings	Unit	Conditions	
Supply voltage	Vcc	2 to 6	V		
Input / Output voltage	V <sub>IN</sub> , V <sub>OUT</sub>	0 to V <sub>CC</sub>	V		
Operating temperature	Та	-40 to 85	O°		
		0 to 1000		V <sub>CC</sub> = 2.0 V	
Input rise / fall time <sup>*1</sup>	t <sub>r</sub> , t <sub>f</sub>	0 to 500	ns	$V_{CC} = 4.5 V$	
		0 to 400		$V_{CC} = 6.0 V$	

Note: 1. This item guarantees maximum limit when one input switches. Waveform: Refer to test circuit of switching characteristics.

### **Electrical Characteristics**

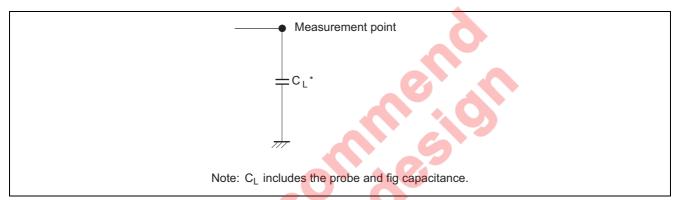
			Ta = 25°C Ta = -40 to+85°C							
ltem	Symbol	V <sub>cc</sub> (V)	Min	Тур	Max	Min	Max	Unit	Test Cor	nditions
Input voltage	VIH	2.0	1.5			1.5	_	V		
		4.5	3.15	ſ	3	3.15	_			
		6.0	4.2	J	_	4.2	_			
	VIL	2.0			0.5	-	0.5	V		
		4.5		_	1.35	-	1.35			
		6.0		_	1.8	-	1.8			
Output voltage	V <sub>OH</sub>	2.0	1.9	2.0	—	1.9	—	V	$Vin = V_{IH} \text{ or } V_{IL}$	I <sub>OH</sub> = –20 µА
		4.5	4.4	4.5	—	4.4	—			
		6.0	5.9	6.0	—	5.9	—			
		4.5	4.18		_	4.13	_			$I_{OH} = -4 \text{ mA}$
		6.0	5.68		_	5.63	_			$I_{OH} = -5.2 \text{ mA}$
	V <sub>OL</sub>	2.0		0.0	0.1		0.1	V	$Vin = V_{IH} \text{ or } V_{IL}$	I <sub>OL</sub> = 20 μA
		4.5		0.0	0.1		0.1			
		6.0	—	0.0	0.1	_	0.1			
		4.5	—	—	0.26	_	0.33			$I_{OL} = 4 \text{ mA}$
		6.0	_	_	0.26	-	0.33			I <sub>OL</sub> = 5.2 mA
Input current	lin	6.0	_	_	±0.1	_	±1.0	μΑ	Vin = V <sub>CC</sub> or GND	
Quiescent supply current	I <sub>CC</sub>	6.0			4.0		40	μA	$Vin = V_{CC} \text{ or } GN$	ID, Iout = 0 $\mu$ A



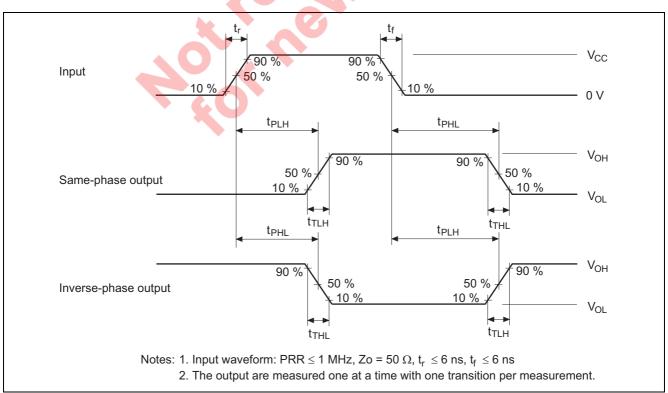
			Т	a = 25°	С	Ta = -40	to +85°C		
Item	Symbol	V <sub>cc</sub> (V)	Min	Тур	Max	Min	Max	Unit	Test Conditions
Propagation delay	t <sub>PLH</sub> , t <sub>PHL</sub>	2.0	_	_	160	—	200	ns	A, B or C to W
time		4.5		17	32	_	40		
		6.0		_	27	—	34		
	t <sub>PLH</sub> , t <sub>PHL</sub>	2.0			150	_	190	ns	Any D to W
		4.5		15	30	_	38		
		6.0			26	_	33		
Output rise/fall	t <sub>TLH</sub> , t <sub>THL</sub>	2.0			75	_	95	ns	
time		4.5		5	15	_	19		
		6.0	_	_	13	—	16		
Input capacitance	Cin	—		5	10	—	10	pF	

# Switching Characteristics ( $C_L = 50 \text{ pF}$ , Input $t_r = t_f = 6 \text{ ns}$ )

## **Test Circuit**

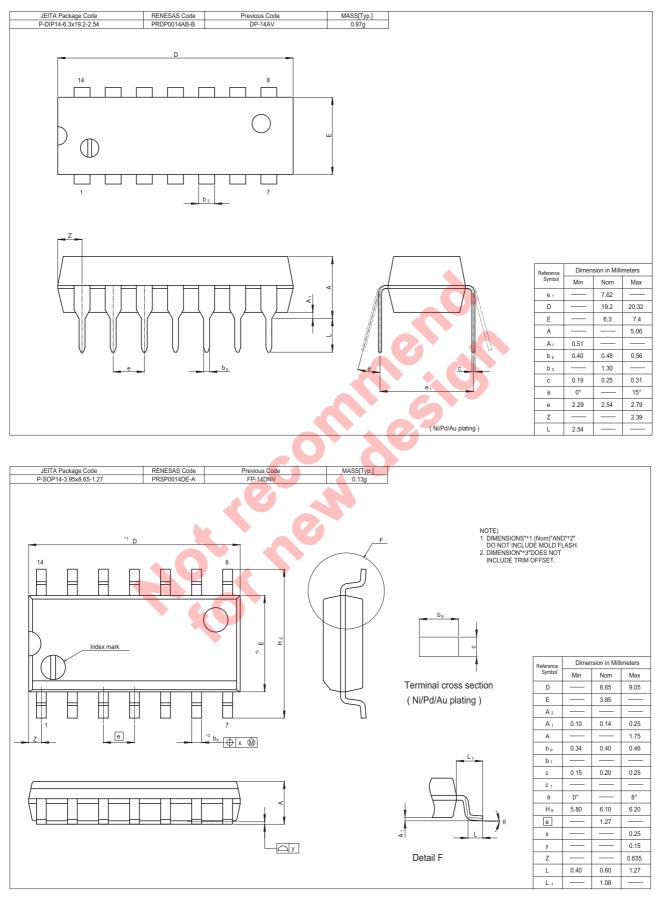


#### Waveforms





### **Package Dimensions**





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